

4,194,304 WORDS×8 BIT DYNAMIC RAM MODULE

**PRELIMINARY**

DESCRIPTION

The THM84000S is a 4,194,304 words by 8 bits dynamic RAM module which assembled 8 pcs of TC514000J on the printed circuit board.

The THM84000S is optimized for application to the systems which are required high density and large capacity such as main memory of the computers and an image memory systems, and to the others which are requested compact size.

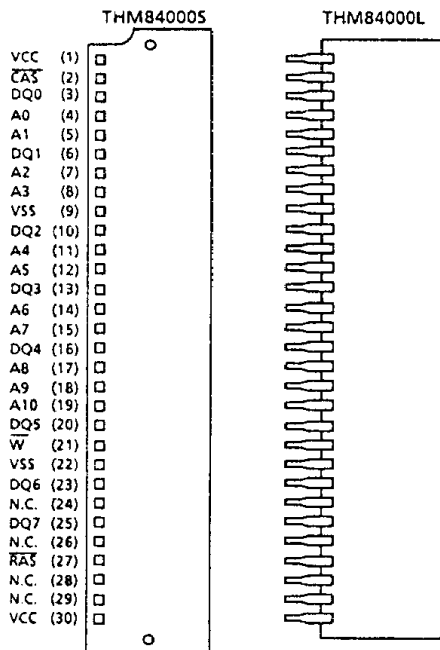
FEATURES

- 4,194,304 words by 8 bits organization
- Fast access time

	THM84000S/L-80	THM84000S/L-10
t <sub>RAC</sub> RAS Access Time	80ns	100ns
t <sub>AA</sub> Column Address Access Time	40ns	50ns
t <sub>CAC</sub> CAS Access Time	20ns	25ns
t <sub>RC</sub> Cycle Time	150ns	180ns
t <sub>PC</sub> Fast Page Mode Cycle Time	50ns	60ns

- Single power supply of 5V±10%
- Low power 4,400mW MAX. Operating (THM84000S/L-80)  
3,740mW MAX. Operating (THM84000S/L-10)  
44mW MAX. Standby
- CAS before RAS refresh, RAS only refresh, Hidden refresh, and Fast Page Mode capability.
- All inputs and outputs TTL compatible
- 1,024 refresh cycles/16ms

PIN CONNECTION (TOP VIEW)

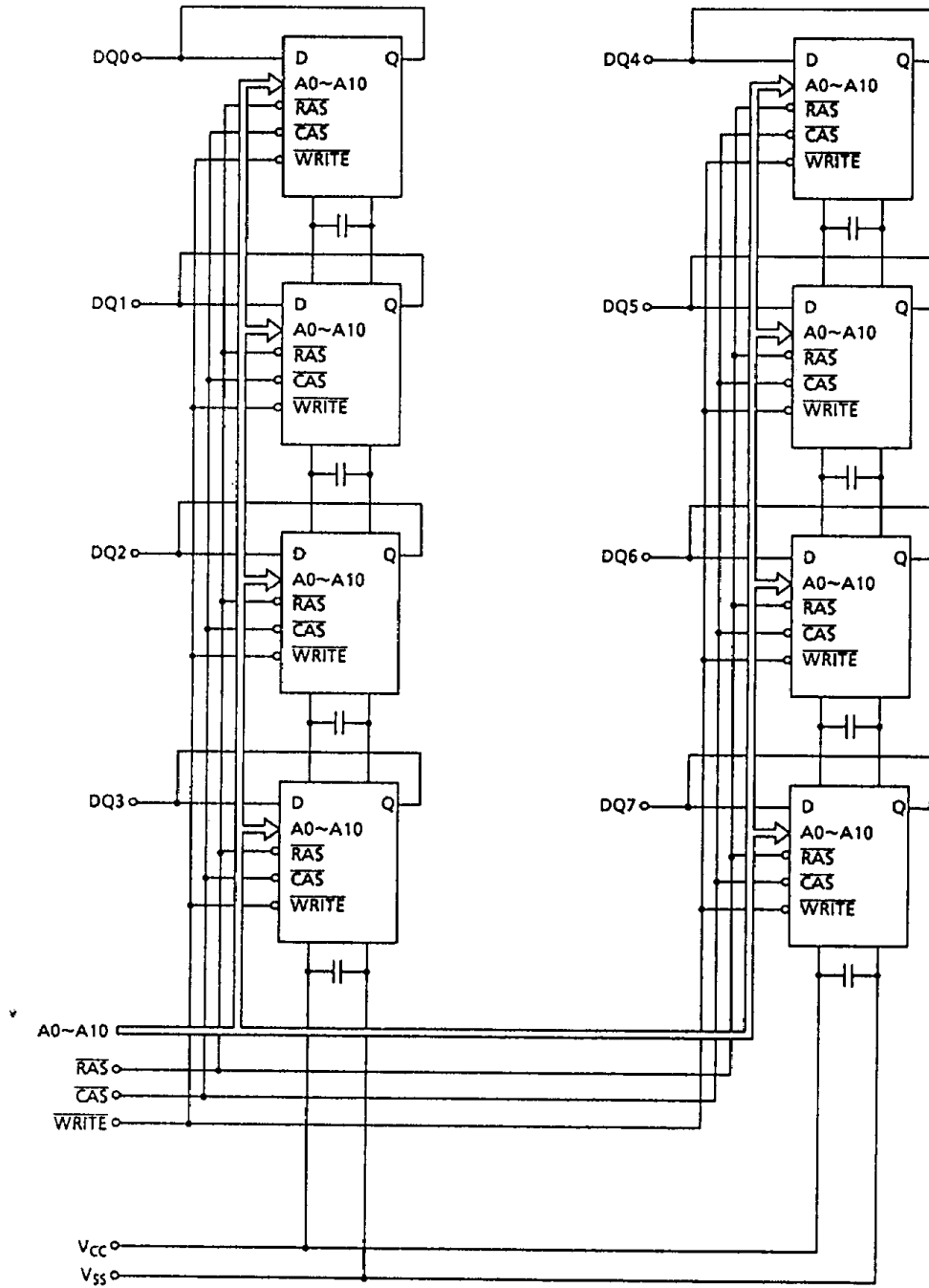


PIN NAMES

A0~A10	Address Inputs
DQ0~DQ7	Data Inputs/Outputs
CAS	Column Address Strobe
RAS	Row Address Strobe
W	Read/Write Input
V <sub>CC</sub>	Power (+ 5V)
V <sub>SS</sub>	Ground
N.C.	No Connection

# THM84000S/L-80, 10

## BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATINGS

ITEM	SYMBOL	RATING	UNITS	NOTES
Input Voltage	V <sub>IN</sub>	-1.0~7.0	V	1
Output Voltage	V <sub>OUT</sub>	-1.0~7.0	V	1
Power Supply Voltage	V <sub>CC</sub>	-1.0~7.0	V	1
Operating Temperature	T <sub>OPR</sub>	0~70	°C	1
Storage Temperature	T <sub>STG</sub>	-55~125	°C	1
Soldering Temperature · Time	T <sub>SOLDER</sub>	260 · 10	°C · sec	1
Power Dissipation	P <sub>D</sub>	4.8	W	1
Short Circuit Output Current	I <sub>OUT</sub>	50	mA	1

RECOMMENDED DC OPERATING CONDITIONS (T<sub>a</sub> = 0~70°C)

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT	NOTES
V <sub>CC</sub>	• Supply Voltage	4.5	5.0	5.5	V	2
V <sub>IH</sub>	Input High Voltage	2.4	-	6.5	V	2
V <sub>IL</sub>	Input Low Voltage	-1.0	-	0.8	V	2

DC ELECTRICAL CHARACTERISTICS (V<sub>CC</sub> = 5V ± 10%, T<sub>a</sub> = 0~70°C)

SYMBOL	PARAMETER	MIN.	MAX.	UNITS	NOTES	
I <sub>CC1</sub>	OPERATING CURRENT Average Power Supply Operating Current ( $\overline{RAS}$ , $\overline{CAS}$ , Address Cycling: t <sub>RC</sub> = t <sub>RC</sub> MIN.)	THM x x x x x - 80	-	800	mA	3, 4
		THM x x x x x - 10	-	680		
I <sub>CC2</sub>	STANDBY CURRENT Power Supply Standby Current ( $\overline{RAS}$ = $\overline{CAS}$ = V <sub>IH</sub> )	-	16	mA		
I <sub>CC3</sub>	$\overline{RAS}$ ONLY REFRESH CURRENT Average Power Supply Current, $\overline{RAS}$ Only Mode ( $\overline{RAS}$ Cycling, $\overline{CAS}$ V <sub>IH</sub> : t <sub>RC</sub> = t <sub>RC</sub> MIN.)	THM x x x x x - 80	-	800	mA	3
		THM x x x x x - 10	-	680		
I <sub>CC4</sub>	FAST PAGE MODE CURRENT Average Power Supply Current, Fast Page Mode ( $\overline{RAS}$ = V <sub>IL</sub> , $\overline{CAS}$ Address Cycling: t <sub>PC</sub> = t <sub>PC</sub> MIN.)	THM x x x x x - 80	-	480	mA	3, 4
		THM x x x x x - 10	-	400		
I <sub>CC5</sub>	STANDBY CURRENT Power Supply Standby Current ( $\overline{RAS}$ = $\overline{CAS}$ = V <sub>CC</sub> - 0.2V)	-	8	mA		
I <sub>CC6</sub>	$\overline{CAS}$ BEFORE $\overline{RAS}$ REFRESH CURRENT Average Power Supply Current, $\overline{CAS}$ Before $\overline{RAS}$ Mode ( $\overline{RAS}$ , $\overline{CAS}$ Cycling: t <sub>RC</sub> = t <sub>RC</sub> MIN.)	THM x x x x x - 80	-	800	mA	3
		THM x x x x x - 10	-	680		
I <sub>I(L)</sub>	INPUT LEAKAGE CURRENT Input Leakage Current, any Input (0V ≤ V <sub>IN</sub> ≤ 6.5V, All Other Pins not under Test = 0V)	-80	80	μA		
I <sub>O(L)</sub>	OUTPUT LEAKAGE CURRENT (D <sub>OUT</sub> is disabled, 0V ≤ V <sub>OUT</sub> ≤ 5.5V)	-20	20	μA		
V <sub>OH</sub>	OUTPUT LEVEL Output "H" Level Voltage (I <sub>OUT</sub> = -5mA)	2.4	-	V		
V <sub>OL</sub>	OUTPUT LEVEL Output "L" Level Voltage (I <sub>OUT</sub> = 4.2mA)	-	0.4	V		

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## ELECTRICAL CHARACTERISTICS AND RECOMMENDED AC OPERATING CONDITIONS

( $V_{CC} = 5V \pm 10\%$ ,  $T_a = 0 \sim 70^\circ C$ ) (Notes 5, 6, 7)

SYMBOL	PARAMETER	THM84000S-80		THM84000S-10		UNIT	NOTES
		MIN.	MAX.	MIN.	MAX.		
$t_{RC}$	Random Read or Write Cycle Time	150	-	180	-	ns	
$t_{PC}$	Fast Page Mode Cycle Time	50	-	60	-	ns	
$t_{RAC}$	Access Time from $\overline{RAS}$	-	80	-	100	ns	8, 13
$t_{CAC}$	Access Time from $\overline{CAS}$	-	20	-	25	ns	8, 13
$t_{AA}$	Access Time from Column Address	-	40	-	50	ns	8, 14
$t_{CPA}$	Access Time from $\overline{CAS}$ Precharge	-	45	-	55	ns	8
$t_{CLZ}$	$\overline{CAS}$ to Output in Low-Z	0	-	0	-	ns	8
$t_{OFF}$	Output Buffer Turn-off Delay	0	20	0	20	ns	9
$t_T$	Transition Time (Rise and Fall)	3	50	3	50	ns	7
$t_{RP}$	$\overline{RAS}$ Precharge Time	60	-	70	-	ns	
$t_{RAS}$	$\overline{RAS}$ Pulse Width	80	10,000	100	10,000	ns	
$t_{RASP}$	$\overline{RAS}$ Pulse Width (Fast Page Mode)	80	200,000	100	200,000	ns	
$t_{RSH}$	$\overline{RAS}$ Hold Time	20	-	25	-	ns	
$t_{CSH}$	$\overline{CAS}$ Hold Time	80	-	100	-	ns	
$t_{CAS}$	$\overline{CAS}$ Pulse Width	20	10,000	25	10,000	ns	
$t_{RCD}$	$\overline{RAS}$ to $\overline{CAS}$ Delay Time	20	60	25	75	ns	13
$t_{RAD}$	$\overline{RAS}$ to Column Address Delay Time	15	40	20	50	ns	14
$t_{CRP}$	$\overline{CAS}$ to $\overline{RAS}$ Precharge Time	5	-	10	-	ns	
$t_{CP}$	$\overline{CAS}$ Precharge Time (Fast Page Mode)	10	-	10	-	ns	
$t_{ASR}$	Row Address Set-Up Time	0	-	0	-	ns	
$t_{RAH}$	Row Address Hold Time	10	-	15	-	ns	
$t_{ASC}$	Column Address Set-Up Time	0	-	0	-	ns	
$t_{CAH}$	Column Address Hold Time	15	-	20	-	ns	
$t_{AR}$	Column Address Hold Time referenced to $\overline{RAS}$	60	-	75	-	ns	
$t_{RAL}$	Column Address to $\overline{RAS}$ Lead Time	40	-	50	-	ns	
$t_{RCS}$	Read Command Set-Up Time	0	-	0	-	ns	
$t_{RCH}$	Read Command Hold Time	0	-	0	-	ns	10
$t_{RRH}$	Read Command Hold Time referenced to $\overline{RAS}$	0	-	0	-	ns	10
$t_{WCH}$	Write Command Hold Time	15	-	20	-	ns	
$t_{WCR}$	Write Command Hold Time referenced to $\overline{RAS}$	60	-	75	-	ns	

ELECTRICAL CHARACTERISTICS AND RECOMMENDED AC OPERATING CONDITIONS

(Continued)

SYMBOL	PARAMETER	THM84000S-80		THM84000S-10		UNIT	NOTES
		MIN.	MAX.	MIN.	MAX.		
t <sub>WP</sub>	Write Command Pulse Width	15	-	20	-	ns	
t <sub>RWL</sub>	Write Command to $\overline{RAS}$ Lead Time	20	-	25	-	ns	
t <sub>CWL</sub>	Write Command to $\overline{CAS}$ Lead Time	20	-	25	-	ns	
t <sub>DS</sub>	Data Set-Up Time	0	-	0	-	ns	11
t <sub>DH</sub>	Data Hold Time	15	-	20	-	ns	11
t <sub>DHR</sub>	Data Hold Time referenced to $\overline{RAS}$	60	-	75	-	ns	
t <sub>REF</sub>	Refresh Period	-	16	-	16	ms	
t <sub>WCS</sub>	Write Command Set-Up Time	0	-	0	-	ns	12
t <sub>CSR</sub>	$\overline{CAS}$ Set-Up Time ( $\overline{CAS}$ before $\overline{RAS}$ Cycle)	5	-	10	-	ns	
t <sub>CHR</sub>	$\overline{CAS}$ Hold Time ( $\overline{CAS}$ before $\overline{RAS}$ Cycle)	15	-	20	-	ns	
t <sub>RPC</sub>	$\overline{RAS}$ to $\overline{CAS}$ Precharge Time	0	-	0	-	ns	
t <sub>CPT</sub>	$\overline{CAS}$ Precharge Time ( $\overline{CAS}$ before $\overline{RAS}$ Counter Test Cycle)	40	-	50	-	ns	
t <sub>WRP</sub>	WRITE to $\overline{RAS}$ Precharge Time ( $\overline{CAS}$ before $\overline{RAS}$ Cycle)	10	-	10	-	ns	
t <sub>WRH</sub>	WRITE to $\overline{RAS}$ Hold Time ( $\overline{CAS}$ before $\overline{RAS}$ Cycle)	10	-	10	-	ns	

CAPACITANCE ( $V_{CC} = 5V \pm 10\%$ ,  $f = 1MHz$ ,  $T_a = 0 \sim 70^\circ C$ )

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
C <sub>I1</sub>	Input Capacitance (A0~A10, $\overline{W}$ , $\overline{CAS}$ , $\overline{RAS}$ )	-	60	pF
C <sub>DQ</sub>	I/O Capacitance (DQ0~DQ7)	-	15	pF

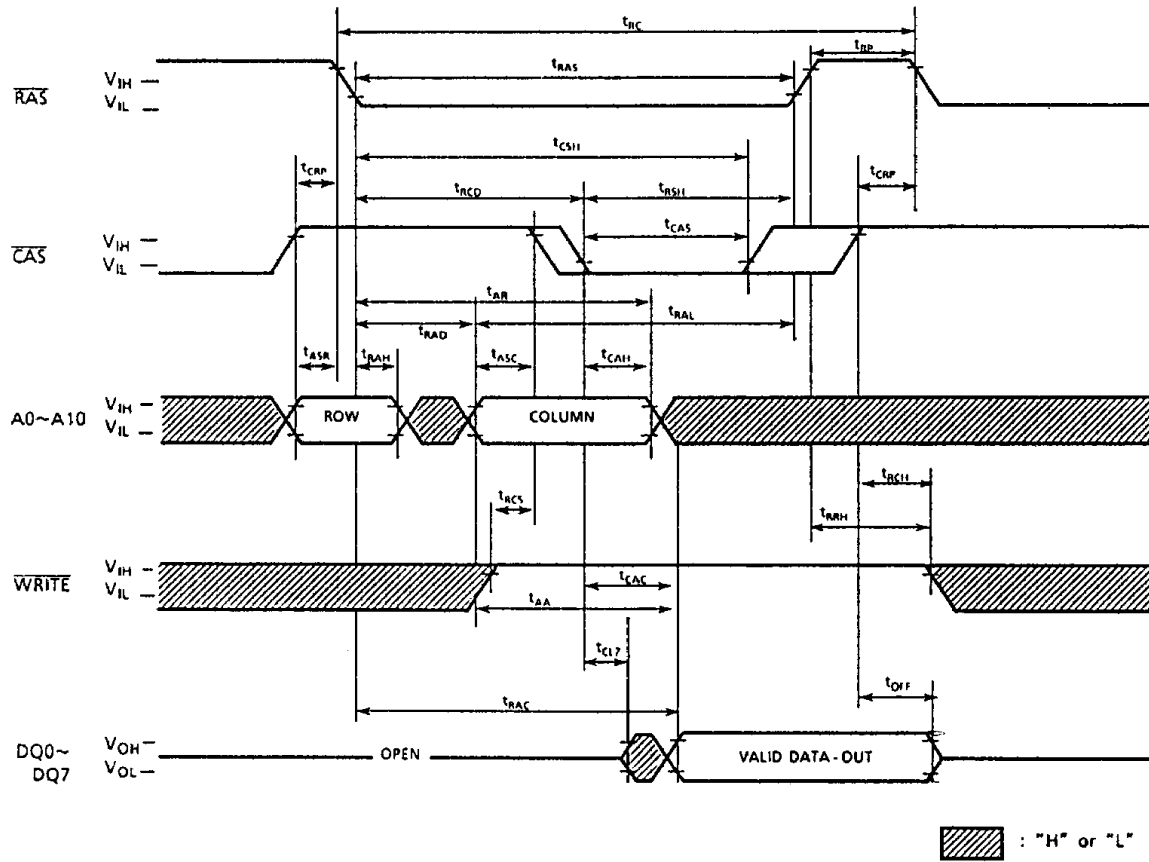
# THM84000S/L-80, 10

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## NOTES:

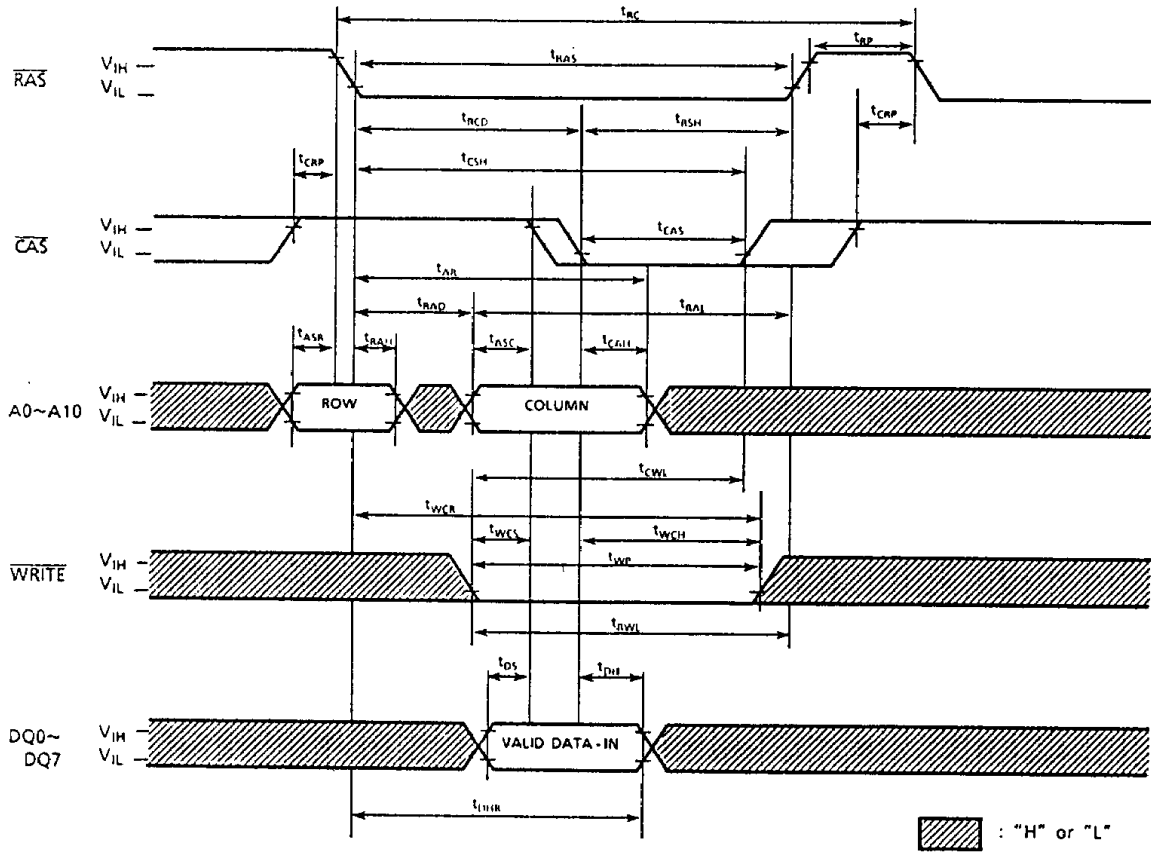
1. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.
2. All voltages are referenced to  $V_{SS}$ .
3.  $I_{CC1}$ ,  $I_{CC3}$ ,  $I_{CC4}$ ,  $I_{CC6}$  depend on cycle rate.
4.  $I_{CC1}$ ,  $I_{CC4}$  depend on output loading. Specified values are obtained with the output open.
5. An initial pause of 200 $\mu$ s is required after power-up followed by 8  $\overline{RAS}$  cycles before proper device operation is achieved. In case of using internal refresh counter, a minimum of 8  $\overline{CAS}$  before  $\overline{RAS}$  initialization cycles instead of 8  $\overline{RAS}$  cycles are required.
6. AC measurements assume  $t_r=5$ ns.
7.  $V_{IH}$  (min.) and  $V_{IL}$  (max.) are reference levels for measuring timing of input signals. Also, transition times are measured between  $V_{IH}$  and  $V_{IL}$ .
8. Measured with a load equivalent to 2 TTL loads and 100pF.
9.  $t_{OFF}$  (max.) defines the time at which the output achieves the open circuit condition and is not referenced to output voltage levels.
10. Either  $t_{RC11}$  or  $t_{RR11}$  must be satisfied for a read cycle.
11. These parameters are referenced to  $\overline{CAS}$  leading edge.
12.  $t_{WCS}$  is not restrictive operating parameters. This is included in the data sheet as electrical characteristics only. If  $t_{WCS} \geq t_{WCS}(\text{min.})$ , the cycle is an early write cycle and data out pin will remain open circuit (high impedance).
13. Operation within the  $t_{RCD}(\text{max.})$  limit insures that  $t_{RAC}(\text{max.})$  can be met.  
 $t_{RCD}(\text{max.})$  is specified as a reference point only: If  $t_{RCD}$  is greater than the specified  $t_{RCD}(\text{max.})$  limit, then access time is controlled by  $t_{CAC}$ .
14. Operation within the  $t_{RAD}(\text{max.})$  limit insures that  $t_{RAC}(\text{max.})$  can be met.  
 $t_{RAD}(\text{max.})$  is specified as a reference point only: If  $t_{RAD}$  is greater than the specified  $t_{RAD}(\text{max.})$  limit, then access time is controlled by  $t_{AA}$ .

READ CYCLE



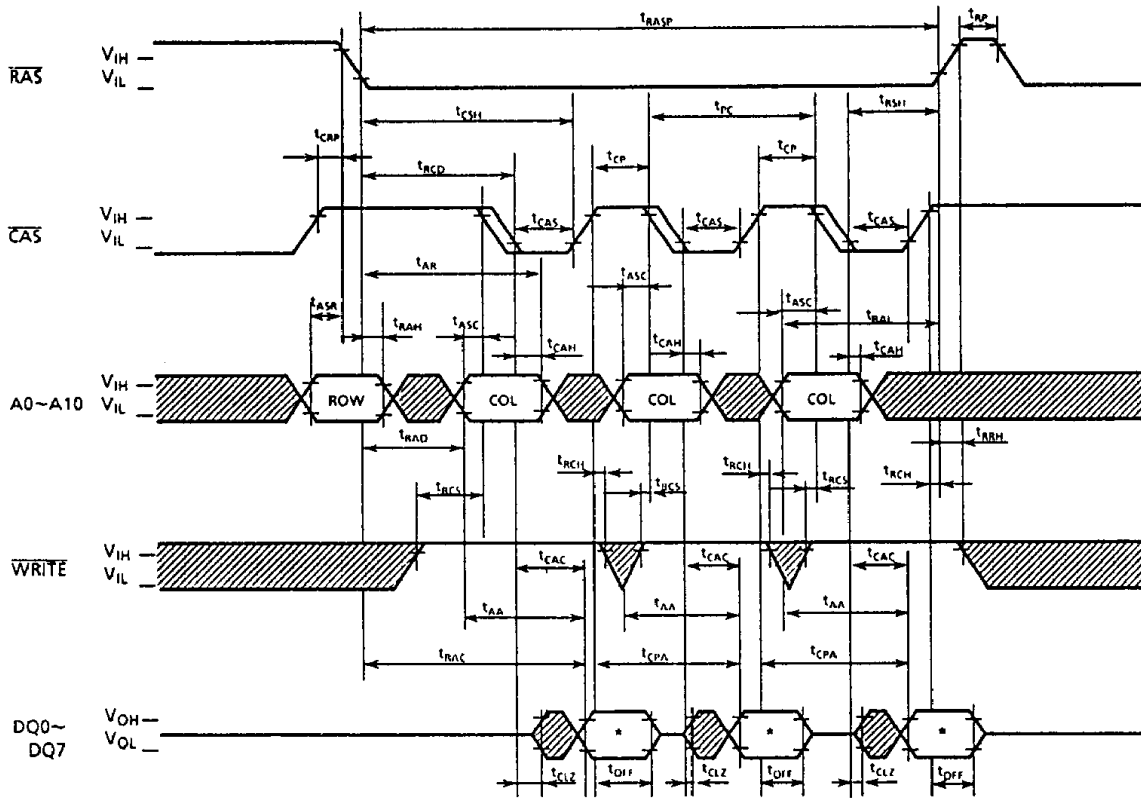
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## EARLY WRITE CYCLE





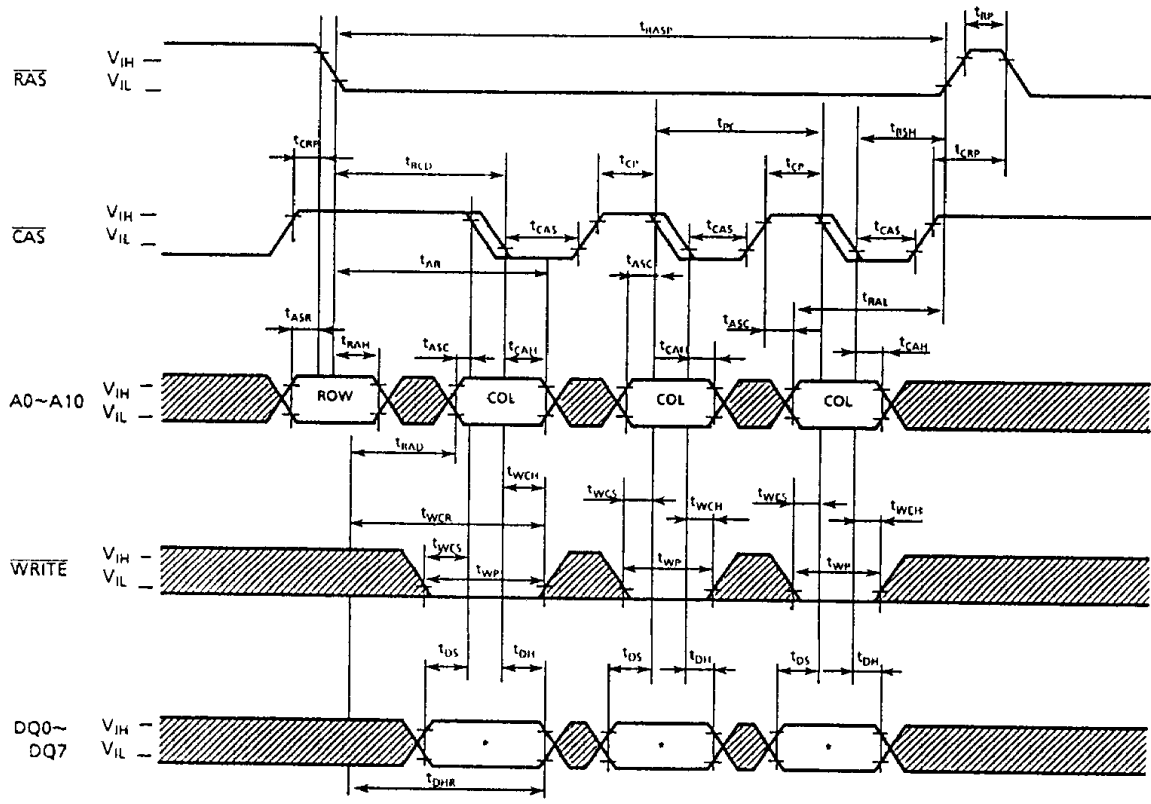
FAST PAGE MODE READ CYCLE



\* VALID DATA OUT

▨ : "H" or "L"

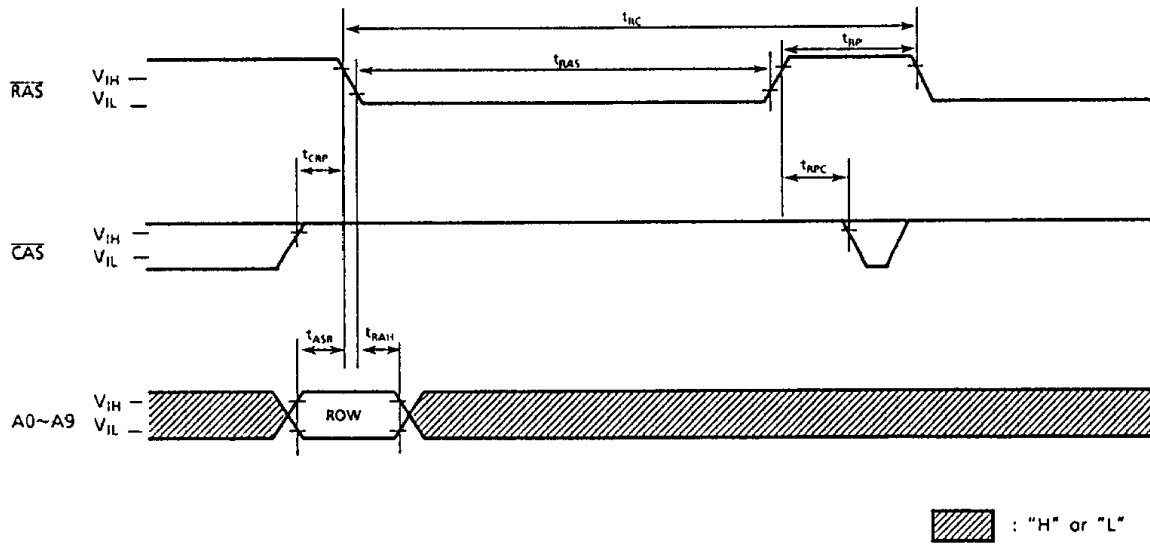
## FAST PAGE MODE WRITE CYCLE (EARLY WRITE)



\* VALID DATA IN

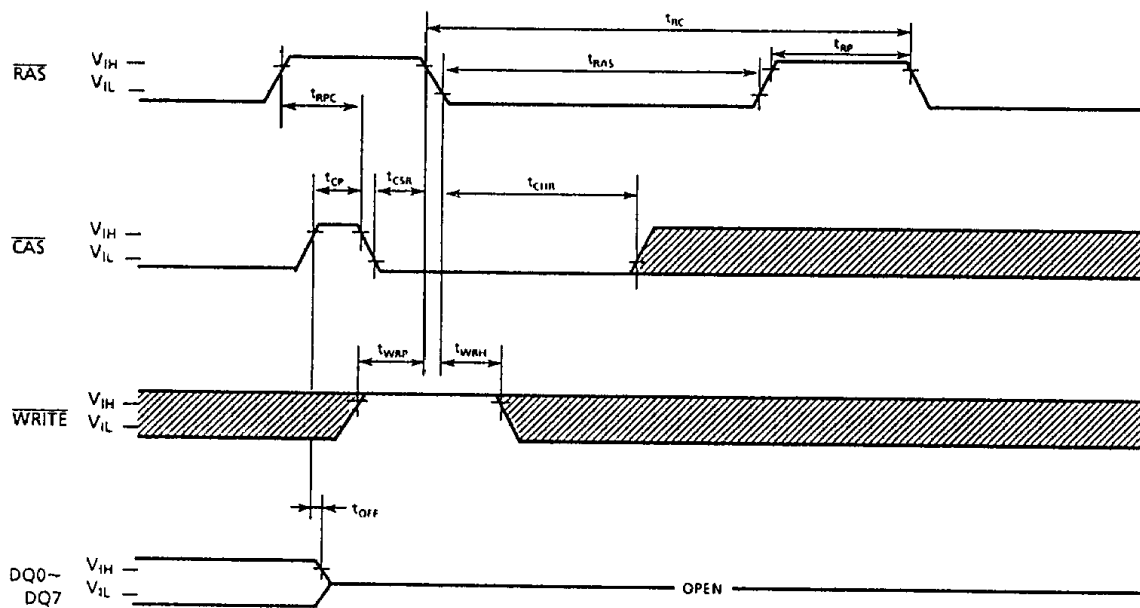
▨ : "H" or "L"

RAS ONLY REFRESH CYCLE




Note:  $\overline{\text{WRITE}}$ , A10 = "H" or "L"

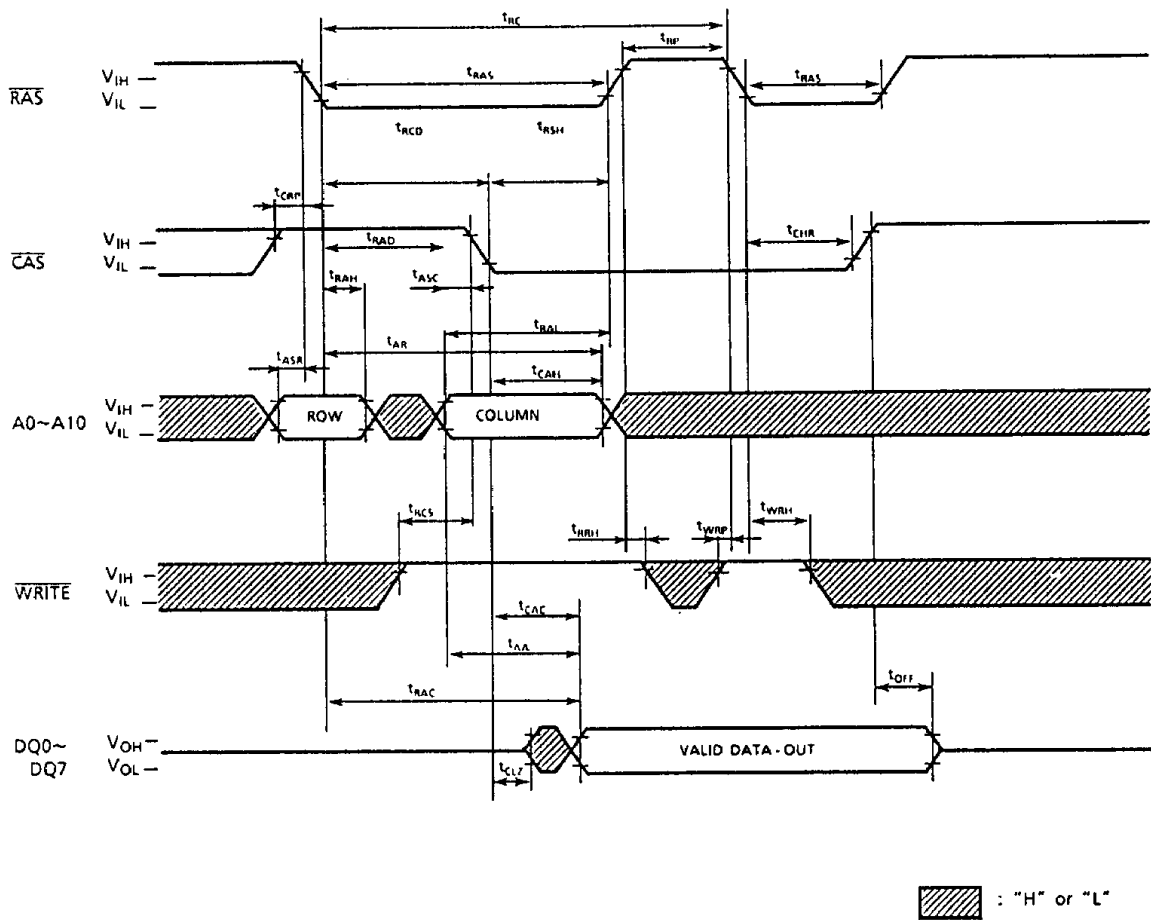
## CAS BEFORE RAS REFRESH CYCLE



Note: A0-A10 = "H" or "L"

 : "H" or "L"

HIDDEN REFRESH CYCLE (READ)





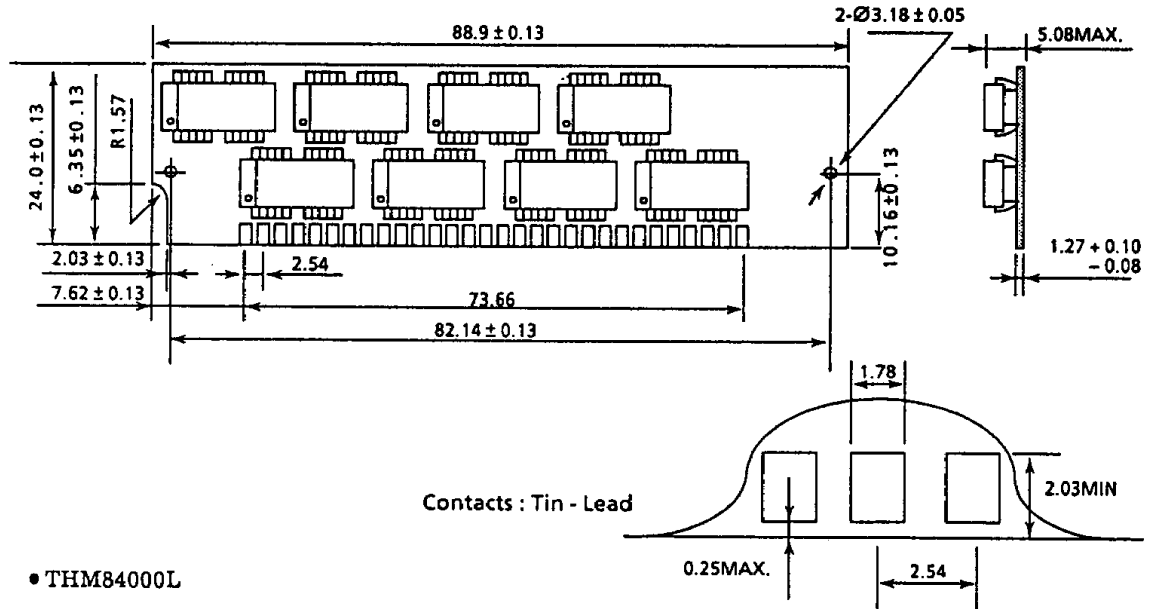


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## OUTLINE DRAWINGS

Unit in mm

### • THM84000S



### • THM84000L

